

## Solid State Devices, Inc.

14701 Firestone Blvd \* La Mirada, Ca 90638 Phone: (562) 404-4474 \* Fax: (562) 404-1773 ssdi@ssdi-power.com \* www.ssdi-power.com

## **Designer's Data Sheet**

# Part Number/Ordering Information <sup>1/</sup> SDR12

Screening 2/

= Not Screened

TX = TX Level

TXV = TXV

S = S Level

## Package Type

\_\_ = Axial

SMS = Surface Mount Square Tab

Family/Voltage

D = 200 V

G = 400V

J = 600 V

K = 800 V

M = 1000 V

## **SDR12 Series**

12 AMPS 200 - 1000 VOLTS 5 μsec STANDARD RECOVERY RECTIFIER

#### **FEATURES:**

- Standard Recovery: 5 μsec maximum
- PIV up to 800 Volts
- High Current Operation up to 12 A
- Hermetically Sealed
- Single Chip Construction
- Low Thermal Resistance
- TX, TXV, and Space Level Screening Available<sup>2/</sup>
- Fast and Ultrafast Recovery Versions Available. Contact Factory.

MAXIMUM RATINGS		Symbol	Value	Units
Peak Repetitive Reverse Voltage and DC Blocking Voltage	SDR12D SDR12G SDR12J SDR12K SDR12M	$egin{array}{c} oldsymbol{V_{RRM}} \ oldsymbol{V_{R}} \end{array}$	200 400 600 800 1000	Volts
Average Rectified Forward Current (Resistive Load, 60 Hz, Sine Wave, T <sub>A</sub> ≤ 55°C)		lo	12	Amps
Peak Surge Current (8.3 ms Pulse, Half Sine Wave, Superimposed on $I_0$ , allow junction to reach equilibrium between pulses, $T_A = 25^{\circ}\text{C}$ )		I <sub>FSM</sub>	150	Amps
Operating and Storage Temperature		T <sub>OP</sub> & T <sub>stg</sub>	-65 to +175	°C
Maximum Thermal Resistance Junction to Lead, L = 0.125" (Axial Lead) Junction to End Tab (Surface Mount )		$R_{ hetaJL}$	6 4	°C/W

 $\underline{1}\!/$  For Ordering Information, Price, Operating Curves, and Availability- Contact Factory.

2/ Screening Based on MIL-PRF-19500. Screening Flow Available on Request.



Surface Mount Square Tab (SMS)



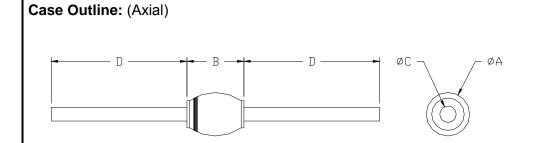




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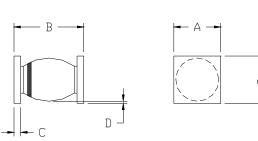
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ELECTRICAL CHARACTERISTICS		Symbol	Min	Max	Unit
Instantaneous Forward Voltage Drop (I <sub>F</sub> = 12 Amps, T <sub>A</sub> = 25°C, 300μsec Pulse)	$T_A = 25^{\circ}C$ $T_A = -55^{\circ}C$	V <sub>F1</sub> V <sub>F2</sub>	<del></del>	1.30 1.50	Volts Volts
Reverse Leakage Current (At Rated V <sub>R</sub> , 300µsec pulse minimum)	$T_A = 25^{\circ}C$ $T_A = 100^{\circ}C$	I <sub>R1</sub>		5.0 200	μ <b>Α</b> μ <b>Α</b>
Junction Capacitance $(V_R = 10 V_{DC}, T_A = 25^{\circ}C, f = 1 MHz)$		CJ	_	80	pF
Reverse Recovery Time (I <sub>F</sub> = 500 mA, I <sub>R</sub> = 1 A, I <sub>RR</sub> = 250 mA, T <sub>A</sub> = 25°C)		t <sub>rr</sub>		5	μs



DIM	MIN	MAX
Α		0.190"
В	0.140"	0.180"
С	0.057"	0.063"
D	0.500"	





DIM	MIN	MAX
Α	0.195"	0.210"
В	0.190"	0.230"
С	0.020"	0.030"
D	0.002"	

Note: Dimensions prior to soldering.

#### **NOTES:**

Consult manufacturing for operating curves.